NSN 5961-01-326-0624

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-326-0624 **Inclosure Material:** Glass **Overall Length:** 0.175 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.075 inches **Function For Which Designed:** Voltage variable capacitor **End Application:** An/grc-17 (v) radio set **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 30.0 reverse voltage, instantaneous and 30.0 breakdown voltage, dc **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current preset and 500.00 nanoamperes forward current, average peak **Power Rating Per Characteristic:** 200.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Test Data Document:** 13499-922-6106 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 13499-580-0629 manufacturers specification Shelf Life: N/a **Unit Of Measure:** Demilitarization: